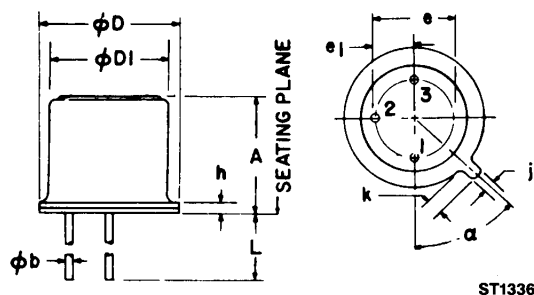


PACKAGE DIMENSIONS



ST1336

DESCRIPTION

The L14C series is a silicon phototransistor mounted in a wide angle, TO-18 package.

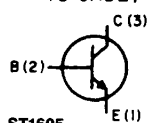
FEATURES

- Hermetically sealed package
- Wide reception angle

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	—	.210	—	5.34	
ϕb	.016	.021	.406	.534	
ϕD	.209	.230	5.30	5.85	
ϕD_1	.178	.195	4.52	4.96	
e	.100 NOM.		2.54 NOM.		2
e_1	.050 NOM.		1.27 NOM.		2
h	—	.030	—	.76	
j	.036	.046	.91	1.17	
k	.028	.048	.71	1.22	1
L	.500	—	12.7	—	
α	45°	45°	45°	45°	3

PACKAGE OUTLINE

(COLLECTOR
CONNECTED
TO CASE)



NOTES:

1. MEASURED FROM MAXIMUM DIAMETER OF DEVICE.
2. LEADS HAVING MAXIMUM DIAMETER .021" (.533mm) MEASURED IN GAUGING PLANE .054" + .001" - .000 (1.37 + .025 - .000mm) BELOW THE REFERENCE PLANE OF THE DEVICE SHALL BE WITHIN .007" (.778mm) THEIR TRUE POSITION RELATIVE TO MAXIMUM WIDTH TAB.
3. FROM CENTERLINE TAB.

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ Unless Otherwise Specified)

Storage Temperature	-65°C to $+150^\circ\text{C}$
Operating Temperature	-65°C to $+125^\circ\text{C}$
Soldering:	
Lead Temperature (Iron)	240°C for 5 sec. ^(3,4,5,6)
Lead Temperature (Flow)	260°C for 10 sec. ^(3,4,6)
Collector-Emitter Breakdown Voltage	50 Volts
Collector-Base Breakdown Voltage	50 Volts
Emitter-Base Breakdown Voltage	7 Volts
Power Dissipation ($T_A = 25^\circ\text{C}$)	300 mW ⁽¹⁾
Power Dissipation ($T_C = 25^\circ\text{C}$)	600 mW ⁽²⁾

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless Otherwise Specified)

(All measurements made under pulse conditions.)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
Collector-Emitter Breakdown	BV_{CEO}	50	—	—	V	$I_C = 10\text{ mA}$, $E_e = 0$
Emitter-Base Breakdown	BV_{EBO}	7.0	—	—	V	$I_E = 100\mu\text{A}$, $E_e = 0$
Collector-Base Breakdown	BV_{CBO}	50	—	—	V	$I_C = 100\mu\text{A}$, $E_e = 0$
Collector-Emitter Leakage	I_{CEO}	—	—	100	nA	$V_{CE} = 20\text{ V}$, $E_e = 0$
Reception Angle at ½ Sensitivity	θ	—	± 40	—	Degrees	
On-State Collector Current L14C1	$I_{C(ON)}$	1.0	—	—	mA	$E_e = 3.0\text{ mW/cm}^2$, $V_{CE} = 5\text{ V}$ ^(7,8)
On-State Collector Current L14C2	$I_{C(ON)}$	0.5	—	—	mA	$E_e = 3.0\text{ mW/cm}^2$, $V_{CE} = 5\text{ V}$ ^(7,8)
On-State Collector Current L14C2	$I_{C(ON)}$	1.0	—	—	mA	$E_e = 6.0\text{ mW/cm}^2$, $V_{CE} = 5\text{ V}$ ^(7,8)
Turn-On Time	t_{on}	—	5	—	μS	$I_C = 2\text{ mA}$, $V_{CC} = 10\text{ V}$, $R_L = 100\Omega$
Turn-Off Time	t_{off}	—	5	—	μS	$I_C = 2\text{ mA}$, $V_{CC} = 10\text{ V}$, $R_L = 100\Omega$
Saturation Voltage	$V_{CE(SAT)}$	—	—	0.40	V	$I_C = 0.40\text{ mA}$, $E_e = 6.0\text{ mW/cm}^2$ ^(7,8)

NOTES

- Derate power dissipation linearly $3.00\text{ mW}/^\circ\text{C}$ above 25°C ambient.
- Derate power dissipation linearly $6.00\text{ mW}/^\circ\text{C}$ above 25°C case.
- RMA flux is recommended.
- Methanol or Isopropyl alcohols are recommended as cleaning agents.
- Soldering iron tip $\frac{1}{16}$ " (1.6 mm) minimum from housing.
- As long as leads are not under any stress or spring tension.
- Light source is a GaAs LED emitting light at a peak wavelength of 940 nm.
- Figure 1 and figure 2 use light source of tungsten lamp at 2870°K color temperature. A GaAs source of 3.0 mW/cm^2 is approximately equivalent to a tungsten source, at 2870°K , of 10 mW/cm^2 .

TYPICAL CHARACTERISTICS

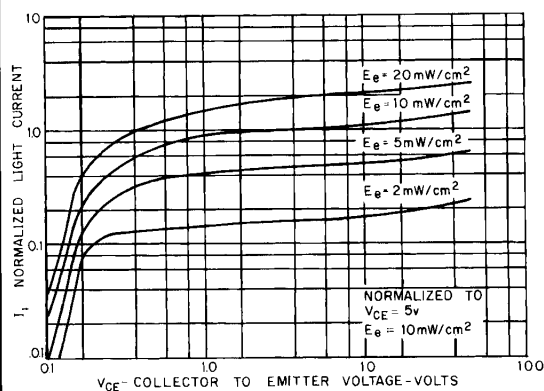


Fig. 1. Light Current vs. Collector to Emitter Voltage ST1062

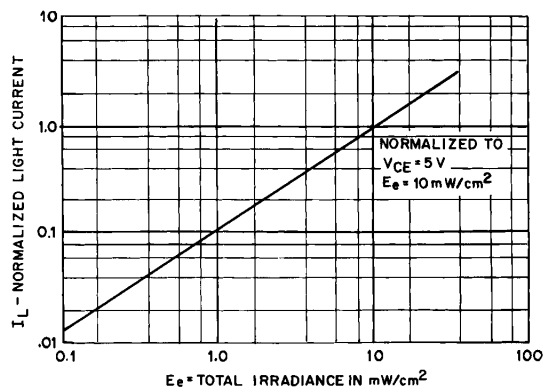


Fig. 2. Normalized Light Current vs. Radiation ST1067

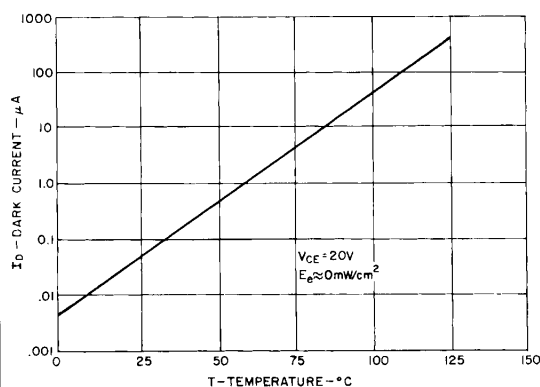


Fig. 3. Dark Current vs. Temperature ST1063

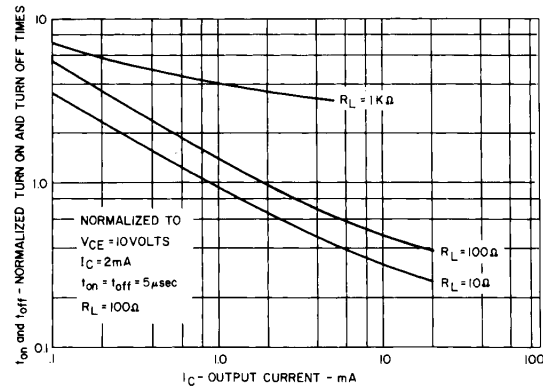


Fig. 4. Switching Speed vs. Output Current ST1066

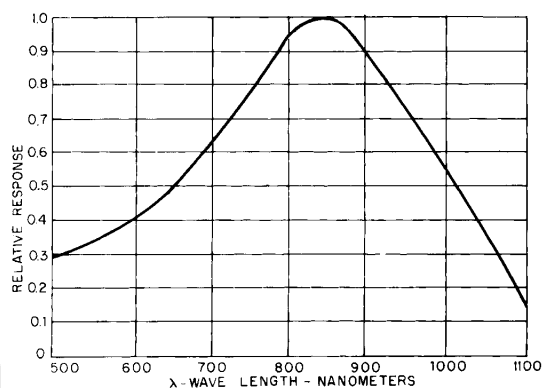


Fig. 5. Spectral Response ST1064

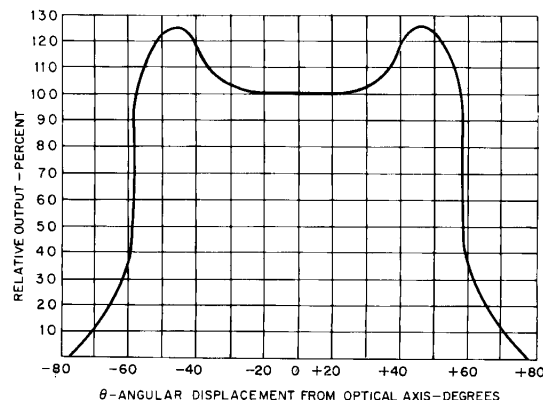


Fig. 6. Angular Response Curve ST1065



HERMETIC SILICON PHOTOTRANSISTOR

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